## RTGN131AP

TRANSISTOR WITH RESISTOR FOR SWITHING APPLICATION SILICON NPN EPITAXIAL TYPE

## DISCRIPTION

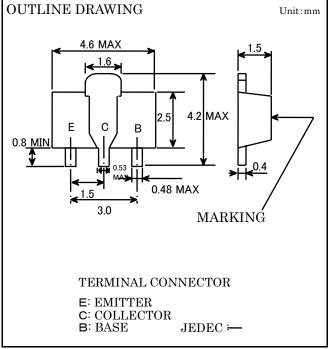
RTGN131AP is a one chip transistor with built-in bias transistor.

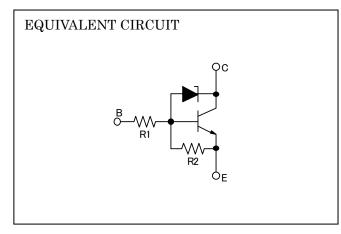
## **FEATURE**

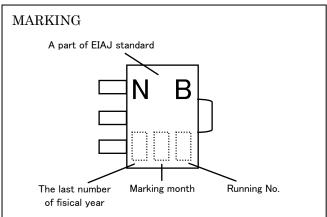
- Built-in bias resistor (R1=1k $\Omega$ ,R2=1k $\Omega$ )
- High collector current IC=1A
- Built-in zener diode between collector and base

## **APPLICATION**

Motor driver circuit







## MAXIMUM RATING(Ta=25°C)

SYMBOL	PARAMETER	RATING	UNIT
$V_{\mathrm{CBO}}$	Collector to Base voltage	60±10	V
$V_{\rm EBO}$	Emitter to Base voltage	10	V
$V_{\rm CEO}$	Collector to Emitter voltage	60±10	V
$I_{\mathrm{C}}$	Collector current (DC)	1	A
$I_{CM}$	Collector current (pulse)	2	A
$P_{\rm C}$	Collector dissipation	500	mW
$T_{\rm j}$	Junction temperature	+150	°C
$T_{ m stg}$	Storage temperature	-55~+150	°C

⟨SMALL-SIGNAL TRANSISTOR⟩

## RTGN131AP

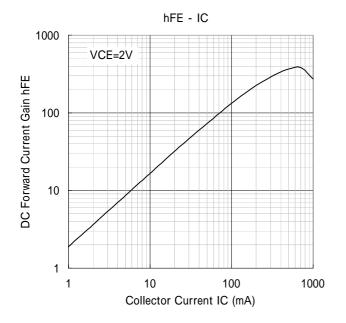
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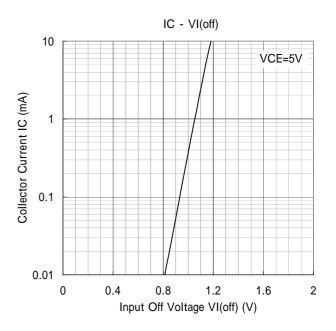
## **ELECTRICAL CHARACTERISTICS**(Ta=25°C)

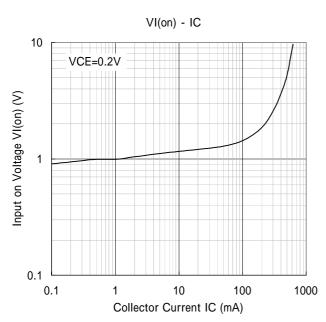
Symbol	Parameter	Test conditions	Limits			Unit
Symbol			Min	Тур	Max	Omi
I <sub>CBO</sub>	Collector cut off current	V <sub>CB</sub> =40V, IE=0	1	1	0.1	uA
$V_{OL}$	Output voltage	VI=5V, I <sub>C</sub> =0.4A	I	I	0.35	٧
$V_{\rm IL}$	Input voltage (OFF)	$V_{CE}$ =5V, $I_{C}$ =100 $\mu$ A	0.3	1	_	٧
hFE1	DC forward current gain	V <sub>CE</sub> =2V, I <sub>C</sub> =0.1A	80	1	1	_
hFE2	DC forward current gain	$V_{CE}$ =2V, $I_{C}$ =0.5A	200	I	ı	_
hFE3	DC forward current gain	$V_{CE}=2V$ , $I_{C}=1A$	200	1	_	_
R <sub>1</sub>	Input resistor	_	0.7	1	1.3	ΚΩ
R <sub>2</sub>	Emitter – Base resistor	_	0.7	1	1.3	ΚΩ

# <SMALL-SIGNAL TRANSISTOR> RTGN131AP

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